## NSN 5961-01-363-4676

**Fiig:** A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-363-4676 **Inclosure Material:** Glass **Overall Length:** Between 0.315 inches and 0.335 inches **Overall Diameter:** Between 0.165 inches and 0.180 inches **Function For Which Designed:** Transient suppressor **End Application:** 6635-01-344-6403 **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 16.2 breakdown voltage, dc and 19.8 breakdown voltage, dc **Current Rating Per Characteristic:** 23.00 amperes source cutoff current universal and 1.00 milliamperes drain current nanoamperes **Power Rating Per Characteristic:** 600.0 watts small-signal input power, common-collector of standard range **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization: No